

14701 Firestone Blvd * La Mirada, CA 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

DESIGNER'S DATA SHEET

Part Number / Ordering Information 1/

L Voltage 20 = 200 V

30 = 300 V

SSR10C <u>30</u>	$\begin{array}{c c} \underline{S.5} & \underline{TX} \\ \hline & \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\$
	Configuration

SSR10C30 Series

10 Amp, 300 Volts Schottky Silicon Carbide

Features:

- High Voltage 300 V
- Very High Operating Temperature, 250°C
- No Recovery Time (tfr or trr)
- High Current Operation, 10 A
- Hermetic Packaging
- TX, TXV, S Level Screening Available

Maximum Ratings ^{2/}		Symbol	Value	Unit
Peak Repetitive and Peak Surge Reverse Voltage	SSR10C20 SSR10C30	V _{RRM} Vrsm	200 300	v
Average Rectified Forward Current (Resistive Load, 60 Hz Sine Wave)		lo	10	Α
Non Repetitive Peak Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on Io)		I _{FSM}	18	Α
Power Dissipation		PD	15	w
Operating & Storage Temperature ^{3/}		T _{op} & T _{stg}	-55 to +250	°C
Maximum Thermal Resistance Junction to Case		R _{ejc}	4.4	°C/W

NOTES:	Cerpack (G)	SMD.5 (S.5)
 For ordering information, price, and availability, contact factory. All electrical characteristics @ 25°C unless otherwise specified. If high temperature operation is desired (> 175°C), consult factory for soldering consideration. 		

NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.	DATA SHEET #: RS0032D	DOCX
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Solid State Devices, Inc.

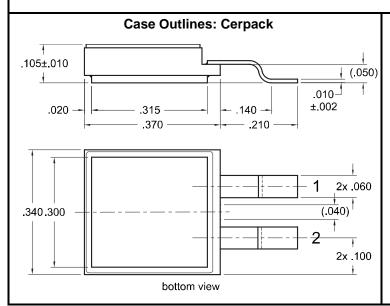
SSR10C30 Series

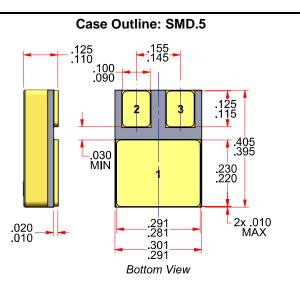
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Electrical Characteristic ^{2/}		Symbol	Min	Тур	Max	Unit
Instantaneous Forward Voltage Drop (T _J = 25°C, 300 μsec pulse)	I _F = 5 A I _F = 10 A	V _{F1} V _{F2}		1.20 1.50	1.32 1.65	v
Instantaneous Forward Voltage Drop $(T_J = 150^{\circ}C, 300 \ \mu sec \ pulse)$	I _F = 5 A I _F = 10 A	V _{F3} V _{F4}		1.18 1.65	1.28 1.85	v
Instantaneous Forward Voltage Drop (T _J = -55°C, 300 μsec pulse)	I _F = 5 A I _F = 10 A	V _{F5} V _{F6}		1.35 1.60	1.45 1.75	v
Reverse Leakage Current (V _R = Rated V _R , T _J = 25°C, 300 µsec min pulse)		I _{R1}		25	100	μΑ
Reverse Leakage Current (V_R = Rated V_R , T_J = 150°C, 300 µsec min pulse)		I _{R2}		100	250	μΑ
Junction Capacitance ($V_R = 10 \text{ Vdc}, T_c = 25^{\circ}\text{C}, f = 1 \text{ MHz}$)		CJ		350	500	pF
Total Capacitive Charge ($V_R = 400 V$, $I_F = 5 A$, di/dt = 200 A/µs, $T_J = 150^{\circ}C$)		Qc		13		nC

NOTES:

- 1/ For ordering information, price, and availability, contact factory.
- 2/ All electrical characteristics @ 25°C unless otherwise specified.
- $\underline{3}$ / If high temperature operation is desired (> 175°C), consult factory for soldering consideration.





Available Part Numbers: SSR10C20S.5 SSR10C20G SSR10C30S.5 SSR10C30G

PIN ASSIGNMENT					
Package	Pin 1	Pin 2	Pin 3 (Tab)		
SMD .5 (S.5)	Cathode	Anode	Anode		
Cerpack (G)	Anode	Anode	Cathode		